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MOSFET - Power, Single N-Channel

40 V, 0.4 mΩ, 553.8 A

NTMTS0D4N04CL

Features

- Small Footprint (8x8 mm) for Compact Design
- Low R_{DS(on)} to Minimize Conduction Losses
- Low Q_G and Capacitance to Minimize Driver Losses
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

Typical Applications

- Power Tools, Battery Operated Vacuums
- UAV/Drones, Material Handling
- BMS/Storage, Home Automation

MAXIMUM RATINGS (T_J = 25°C unless otherwise noted)

Parameter			Symbol	Value	Unit
Drain-to-Source Voltage			V _{DSS}	40	V
Gate-to-Source Voltage			V _{GS}	±20	V
Continuous Drain	Steady State	$T_{C} = 25^{\circ}C$	I _D	553.8	А
Current $R_{\theta JC}$ (Note 2)		$T_{C} = 100^{\circ}C$	I _D	394.8	А
Power Dissipation $R_{\theta JC}$ (Note 2)		T _C = 25°C	PD	244	W
		$T_{C} = 100^{\circ}C$	PD	122	W
Continuous Drain Current $R_{\theta JA}$ (Notes 1, 2) Power Dissipation	Steady State	$T_A = 25^{\circ}C$	I _D	79.8	А
		T _A = 100°C	۱ _D	56.4	А
		$T_A = 25^{\circ}C$	PD	5.0	W
R _{θJA} (Notes 1, 2)		T _A = 100°C	PD	2.5	W
Pulsed Drain Current	T _A = 25	°C, t _p = 10 μs	I _{DM}	900	А
Operating Junction and Storage Temperature Range			T _J , T _{stg}	–55 to + 175	°C
Source Current (Body Diode)			۱ _S	203.4	А
Single Pulse Drain-to-Source Avalanche Energy (I _{L(pk)} = 70 A)			E _{AS}	4454	mJ
Lead Temperature for Soldering Purposes (1/8" from case for 10 s)		ΤL	260	°C	

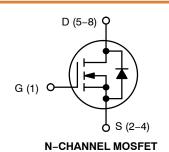
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

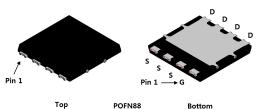
THERMAL RESISTANCE MAXIMUM RATINGS

Parameter	Symbol	Value	Unit
Junction-to-Case - Steady State (Note 2)	$R_{\theta JC}$	0.61	°C/W
Junction-to-Ambient - Steady State (Note 2)	$R_{\theta JA}$	30.1	

1. Surface-mounted on FR4 board using a 1 in² pad size, 1 oz. Cu pad.

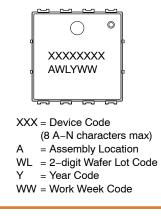
V _{(BR)DSS}	R _{DS(ON)} MAX	I _D MAX
40 V	0.4 mΩ @ 10 V	
	0.64 mΩ @ 4.5 V	553.8 A





POWER 88 CASE 507AP

MARKING DIAGRAM



ORDERING INFORMATION

See detailed ordering, marking and shipping information in the package dimensions section on page 5 of this data sheet.

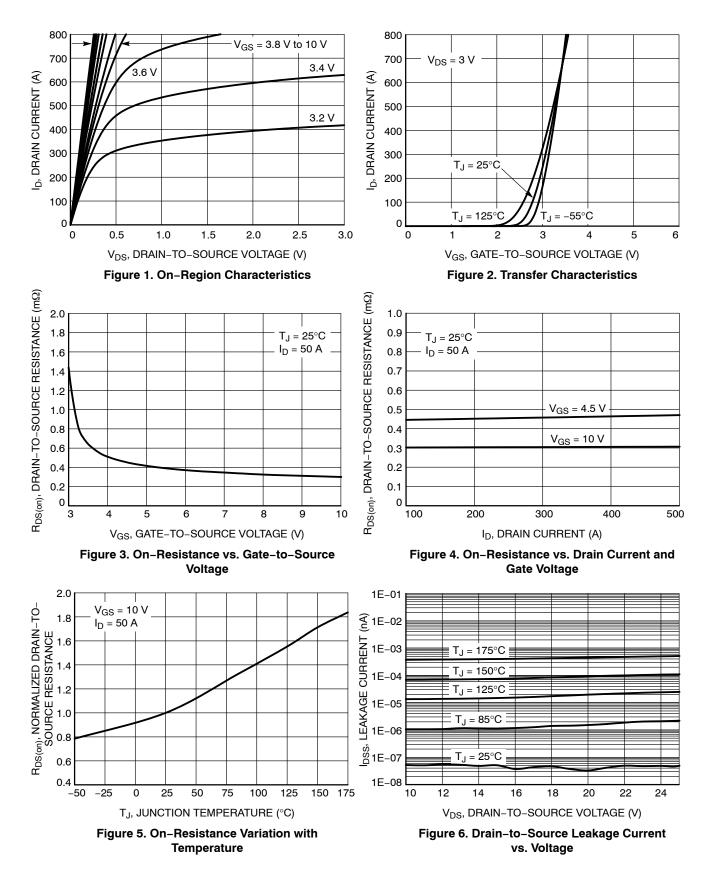
2. The entire application environment impacts the thermal resistance values shown, they are not constants and are only valid for the particular conditions noted.

ELECTRICAL CHARACTERISTICS (T _J	$I = 25^{\circ}C$ unless otherwise specified)
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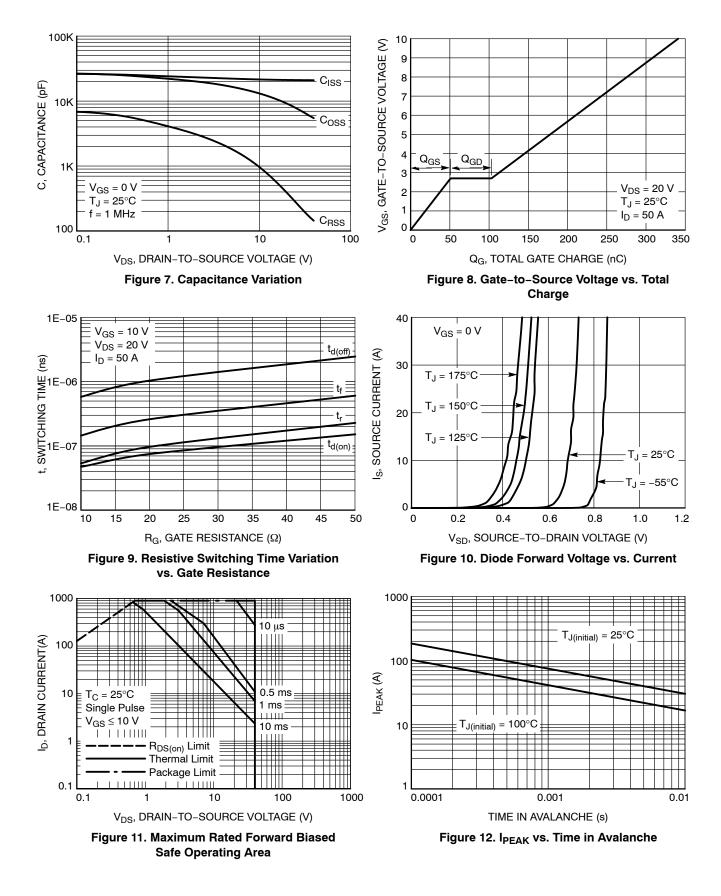
Parameter	Symbol	Test Condition		Min	Тур	Max	Unit	
OFF CHARACTERISTICS		•		-			•	
Drain-to-Source Breakdown Voltage	V _{(BR)DSS}	V_{GS} = 0 V, I _D = 250 µA		40			V	
Drain-to-Source Breakdown Voltage Temperature Coefficient	V _{(BR)DSS} / T _J	$I_D = 250 \ \mu\text{A}, \text{ ref to } 25^\circ\text{C}$			8.86		mV/°C	
Zero Gate Voltage Drain Current	I _{DSS}	V _{GS} = 0 V,	$T_J = 25^{\circ}C$			10		
		V _{DS} = 32 V	T _J = 125°C			250	μΑ	
Gate-to-Source Leakage Current	I _{GSS}	$V_{DS} = 0 V, V_{GS}$	_S = 20 V			100	nA	
ON CHARACTERISTICS (Note 3)								
Gate Threshold Voltage	V _{GS(TH)}	$V_{GS} = V_{DS}, I_D$	= 250 μA	1.0		2.5	V	
Negative Threshold Temperature Coefficient	V _{GS(TH)} /T _J	I _D = 250 μA, re	ef to 25°C		-6.24		mV/°C	
Drain-to-Source On Resistance	R _{DS(on)}	V _{GS} = 10 V	I _D = 50 A		0.3	0.4		
		V _{GS} = 4.5 V	l _D = 50 A		0.45	0.64	mΩ	
Forward Transconductance	9 FS	V _{DS} =5 V, I _D	= 50 A		330		S	
Gate Resistance	R _G	T _A = 25	°C		1.0		Ω	
CHARGES, CAPACITANCES & GATE RESIS	TANCE							
Input Capacitance	C _{ISS}				20600			
Output Capacitance	C _{OSS}	V _{GS} = 0 V, f = 1 MH	lz, V _{DS} = 20 V		9500		pF	
Reverse Transfer Capacitance	C _{RSS}				390			
Total Gate Charge	Q _{G(TOT)}	V_{GS} = 4.5 V, V_{DS} = 20 V; I_{D} = 50 A			163		nC	
Threshold Gate Charge	Q _{G(TH)}				29.8			
Gate-to-Source Charge	Q _{GS}				51		1	
Gate-to-Drain Charge	Q _{GD}	V_{GS} = 10 V, V_{DS} = 20 V; I_{D} = 50 A			52.1		nC	
Total Gate Charge	Q _{G(TOT)}				341			
Voltage Plateau	V _{GP}				2.7		V	
SWITCHING CHARACTERISTICS, V _{GS} = 4.5	V (Note 4)	•		-				
Turn-On Delay Time	t _{d(ON)}				110		- ns	
Rise Time	t _r	V _{GS} = 4.5 V, V _D	s = 20 V.		147			
Turn-Off Delay Time	t _{d(OFF)}	$I_{\rm D} = 50 \text{ A}, \text{ R}_{\rm C}$	$r_{3} = 6 \Omega$		217			
Fall Time	t _f				107			
SWITCHING CHARACTERISTICS, V _{GS} = 10	V (Note 4)							
Turn-On Delay Time	t _{d(ON)}				45.6			
Rise Time	t _r	V _{GS} = 10 V, V _D	s = 20 V.		39.8		1	
Turn-Off Delay Time	t _{d(OFF)}	$I_{\rm D} = 50 \text{ A}, R_{\rm G} = 6 \Omega$			382		ns	
Fall Time	t _f				96.4		1	
DRAIN-SOURCE DIODE CHARACTERISTIC	s				•			
Forward Diode Voltage	V _{SD}	V _{GS} = 0 V,	T _J = 25°C		0.75	1.2	V	
		$I_{\rm S} = 50 \rm A$	T _J = 125°C		0.58			
Reverse Recovery Time	t _{RR}	V _{GS} = 0 V, dlS/dt = 100 A/µs, I _S = 50 A			117			
Charge Time	ta				87		ns	
Discharge Time	t _b				30		1	
Reverse Recovery Charge	Q _{RR}				336		nC	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 3. Pulse Test: pulse width $\leq 300 \ \mu$ s, duty cycle $\leq 2\%$. 4. Switching characteristics are independent of operating junction temperatures.

TYPICAL CHARACTERISTICS



TYPICAL CHARACTERISTICS



TYPICAL CHARACTERISTICS

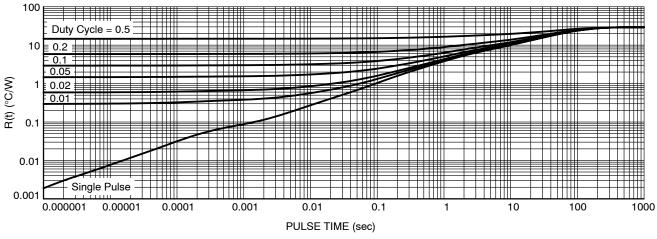


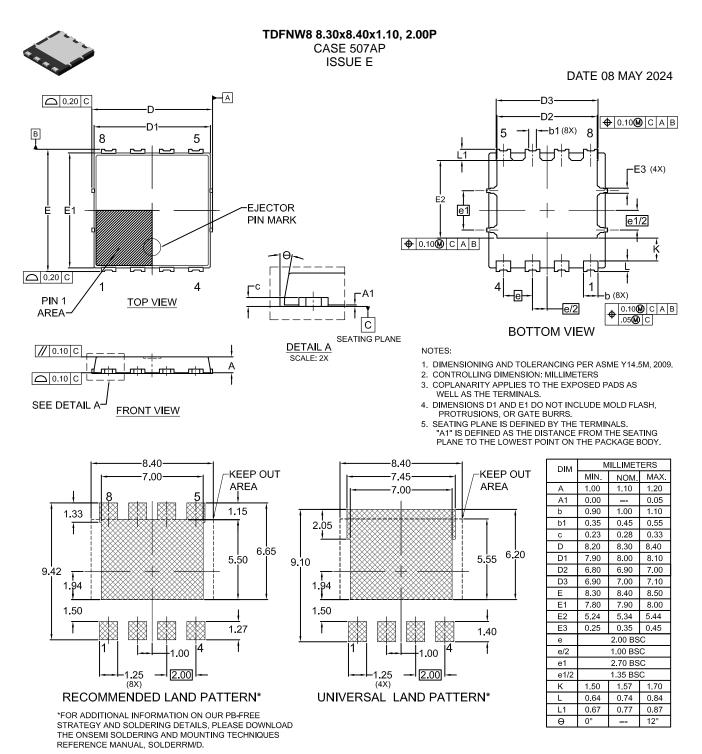
Figure 13. Thermal Characteristics

DEVICE ORDERING INFORMATION

Device	Marking	Package	Shipping [†]
NTMTS0D4N04CLTXG	0D4N04CL	POWER 88 (Pb–Free)	TBD / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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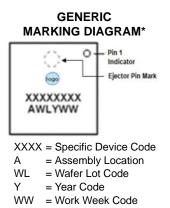
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DATE 08 MAY 2024



*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " •", may or may not be present. Some products may not follow the Generic Marking.

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